FAIRCHILD

SEMICONDUCTOR

KSC5042

High Voltage Switchihg Dynamic Focus Application

- High Collector-Emitter Breakdown Voltage : BV_{CEO}=900V
- Small C_{ob} =2.8pF(Typ.)
 Wide S.O.A
- High reliability



1.Base 2.Collector 3.Emitter

NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

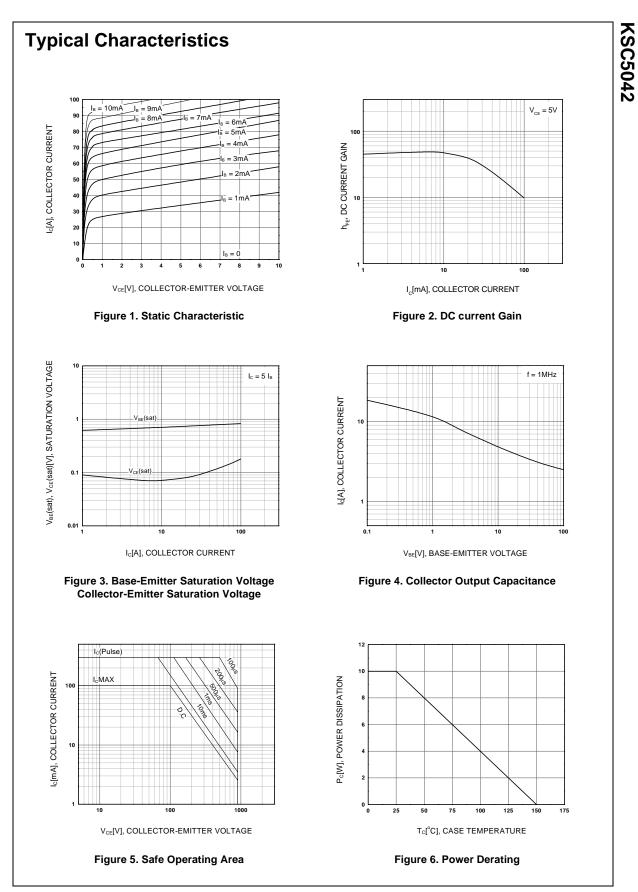
Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	1500	V	
V _{CEO}	Collector-Emitter Voltage	900	V	
V _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current (DC)	100	mA	
I _{CP}	Collector Current (Pulse)	300	mA	
P _C	Collector Dissipation (T _C =25°C)	10	W	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	- 55 ~ 150	°C	

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = 1 \text{ mA}, I_{E} = 0$	1500			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{C} = 5mA, I_{B} = 0$	900			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E}=1mA, I_{C}=0$	5			V
I _{CBO}	Collector Cut-off Current	$V_{CB}=900V, I_{E}=0$			10	μA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			10	μA
h _{FE}	*DC Current Gain	V _{CE} =5V, I _C = 10mA	30			
V _{CE} (sat)	*Collector-Emitter Saturation Voltage	I_{C} =20mA, I_{B} = 4mA			5	V
V _{BE} (sat)	*Base-Emitter Saturation Voltage	I_{C} =20mA, I_{B} = 4mA			2	V
C _{ob}	Output Capacitance	V _{CB} =100V, f = 1MHz		2.8		pF

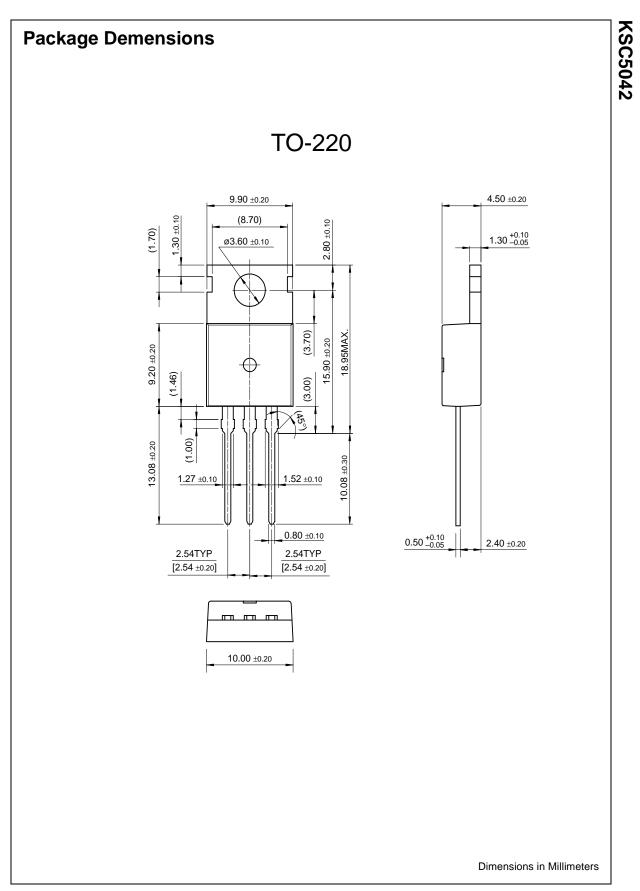
* Pulse test: PW = 300µs, Duty Cycle = 2% pulsed

KSC5042



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Rev. A1, June 2001



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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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Applications

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Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method	
KSC5042TU	Full Production	\$0.361	TO-220	3	RAIL	
* 1 000 sizes Destates Division						

* 1,000 piece Budgetary Pricing

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